

HN3C51F-GR(TE85L,F Information


For Reference Only

Part Number HN3C51F-GR(TE85L,F
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Arrays
Description TRANS 2NPN 120V 0.1A SM6
Package SC-74, SOT-457
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


HN3C51F-GR(TE85L,F Specifications

Manufacturer Part Number	HN3C51F-GR(TE85L,F
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays
Package	SC-74, SOT-457
Series	-
Transistor Type	2 NPN (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	120V
Vce Saturation (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2mA, 6V
Power - Max	300mW
Frequency - Transition	100MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SC-74, SOT-457
Supplier Device Package	SM6

[Report errors?](#)

HN3C51F-GR(TE85L,F Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

HN3C51F-GR(TE85L,F Payment Methods



HN3C51F-GR(TE85L,F Shipping Methods



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